

### Product Summary

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
60V	1.6mΩ@10V	318A

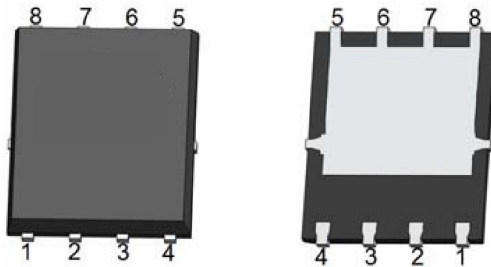
### Feature

- Excellent gate charge x  $R_{DS(on)}$  product (FOM)
- Very low on-resistance  $R_{DS(on)}$

### Application

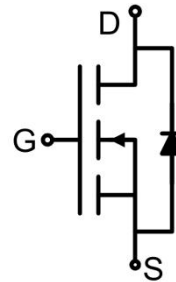
- DC-DC converter
- Ideal for high-frequency switching and synchronous rectification

### Package

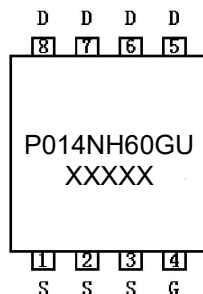


PDFN5\*6-8L

### Circuit diagram



### Marking



### Absolute maximum ratings (T<sub>c</sub>=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	60	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Continuous Drain Current	I <sub>D</sub>	318	A
Continuous Drain Current (T <sub>c</sub> =100°C)	I <sub>D</sub> (100°C)	200	A
Pulsed Drain Current <sup>1)</sup>	I <sub>DM</sub>	1272	A
Power Dissipation	P <sub>D</sub>	280	W
Thermal Resistance, Junction-to-Case	R <sub>θJC</sub>	0.45	°C/W
Single pulse avalanche energy <sup>5)</sup>	E <sub>AS</sub>	520	mJ
Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ +150	°C

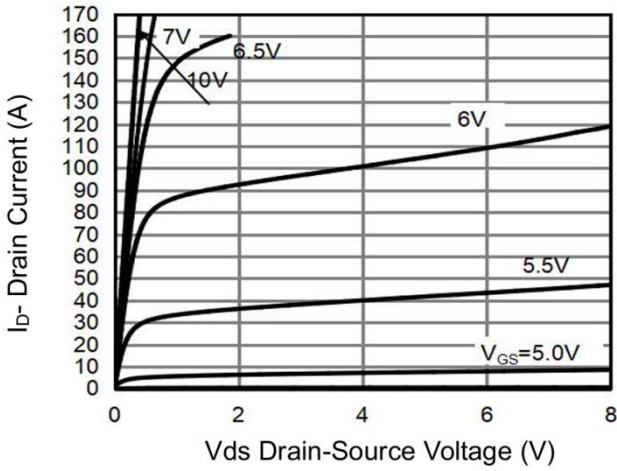
### Electrical characteristics (T<sub>c</sub>=25 °C, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
<b>Static Characteristics</b>						
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =250μA	60			V
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> =60V, V <sub>GS</sub> = 0V			1	μA
Gate-body leakage current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> = 0V			±100	nA
Gate threshold voltage <sup>3)</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	2.0	3.0	4.0	V
Drain-source on-resistance <sup>3)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A		1.3	1.6	mΩ
Forward Transconductance <sup>3)</sup>	g <sub>FS</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =20A		60		S
<b>Dynamic characteristics<sup>4)</sup></b>						
Input Capacitance	C <sub>iSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V, f =1MHz		5478		pF
Output Capacitance	C <sub>oss</sub>			2012		
Reverse Transfer Capacitance	C <sub>rSS</sub>			178		
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =20A		97.7		nC
Gate-Source Charge	Q <sub>gs</sub>			29.7		
Gate-Drain Charge	Q <sub>gd</sub>			31.3		
Turn-on delay time	t <sub>d(on)</sub>	V <sub>DD</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =20A, R <sub>G</sub> =4.7Ω		24		nS
Turn-on rise time	t <sub>r</sub>			21		
Turn-off delay time	t <sub>d(off)</sub>			45		
Turn-off fall time	t <sub>f</sub>			18		
<b>Source-Drain Diode characteristics</b>						
Diode Forward Current <sup>2)</sup>	I <sub>S</sub>				318	A
Diode Forward voltage <sup>3)</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =20A			1.2	V
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> =25°C, I <sub>F</sub> =40A, di/dt =100A/μs <sup>3)</sup>		60		nS
Reverse Recovery Charge	Q <sub>rr</sub>			80		nC

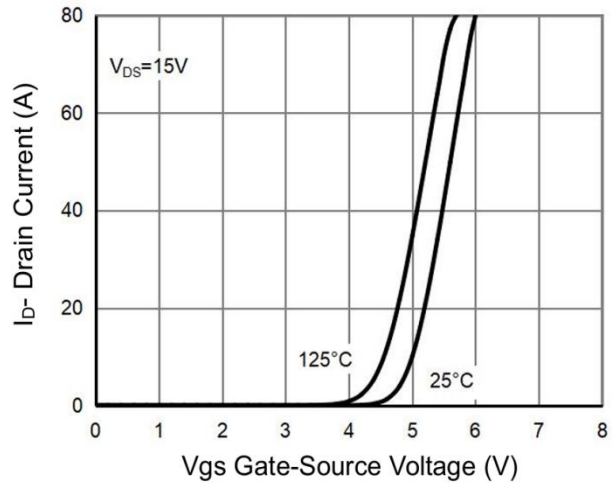
Notes:

- 1) Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2) Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3) Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
- 4) Guaranteed by design, not subject to production
- 5) EAS condition : T<sub>J</sub>=25°C, V<sub>DD</sub>=30V, V<sub>G</sub>=10V, L=0.5mH, R<sub>G</sub>=25Ω

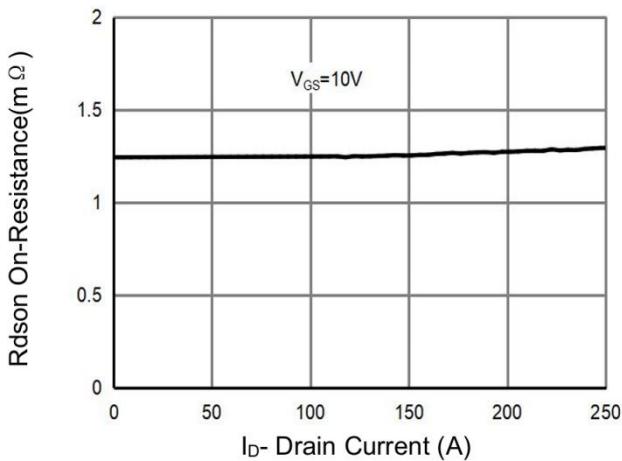
## Typical Characteristics



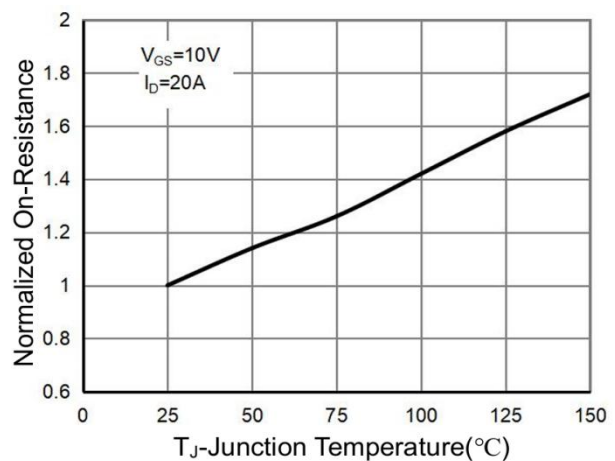
**Figure 1 Output Characteristics**



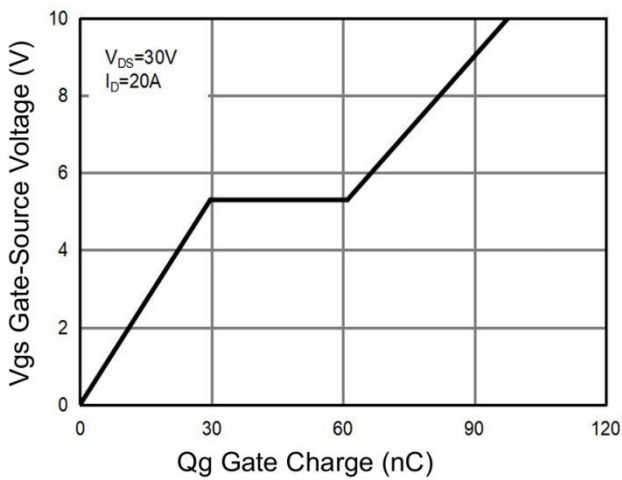
**Figure 2 Transfer Characteristics**



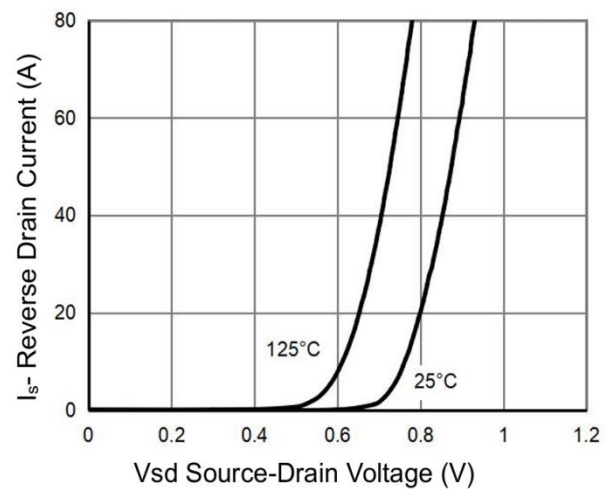
**Figure 3 Rdson- Drain Current**



**Figure 4 Rdson-Junction Temperature**

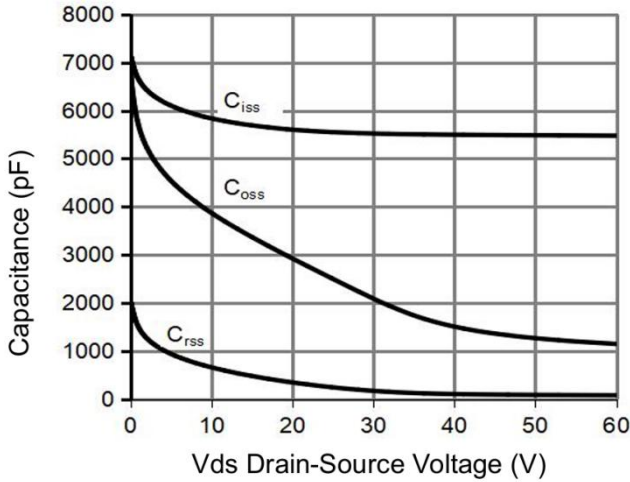


**Figure 5 Gate Charge**

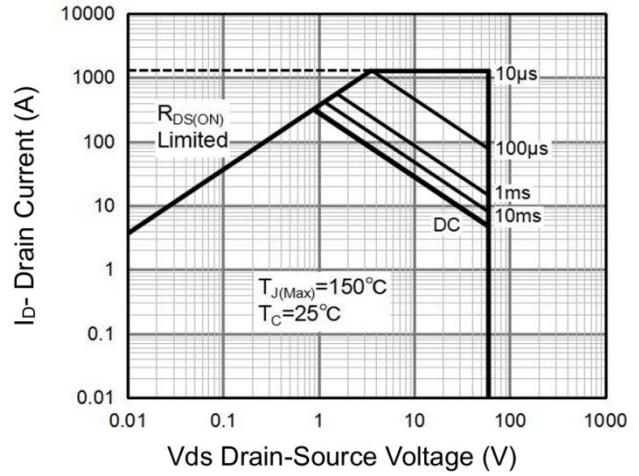


**Figure 6 Source- Drain Diode Forward**

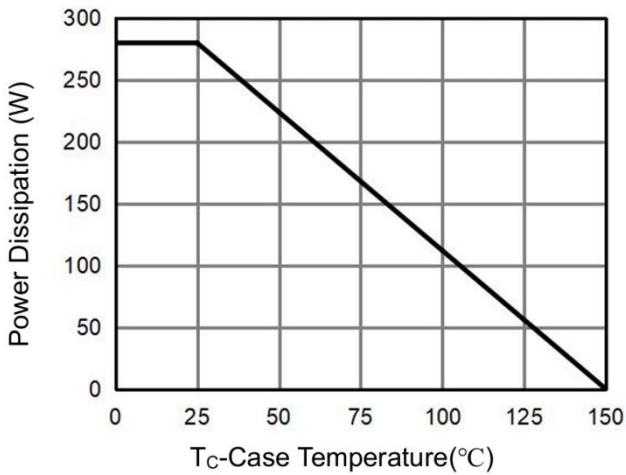
## Typical Characteristics



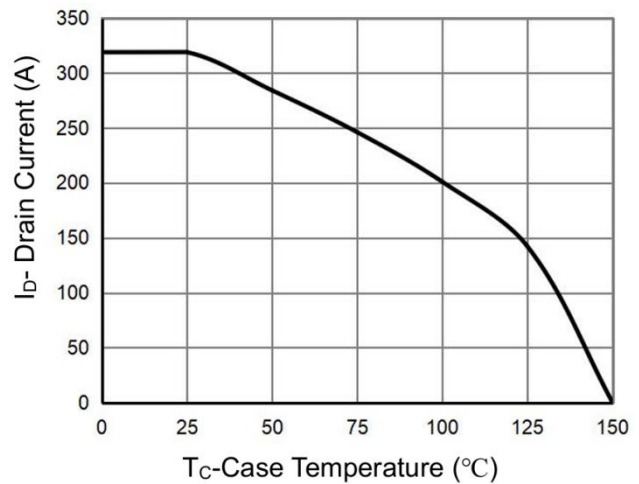
**Figure 7 Capacitance vs Vds**



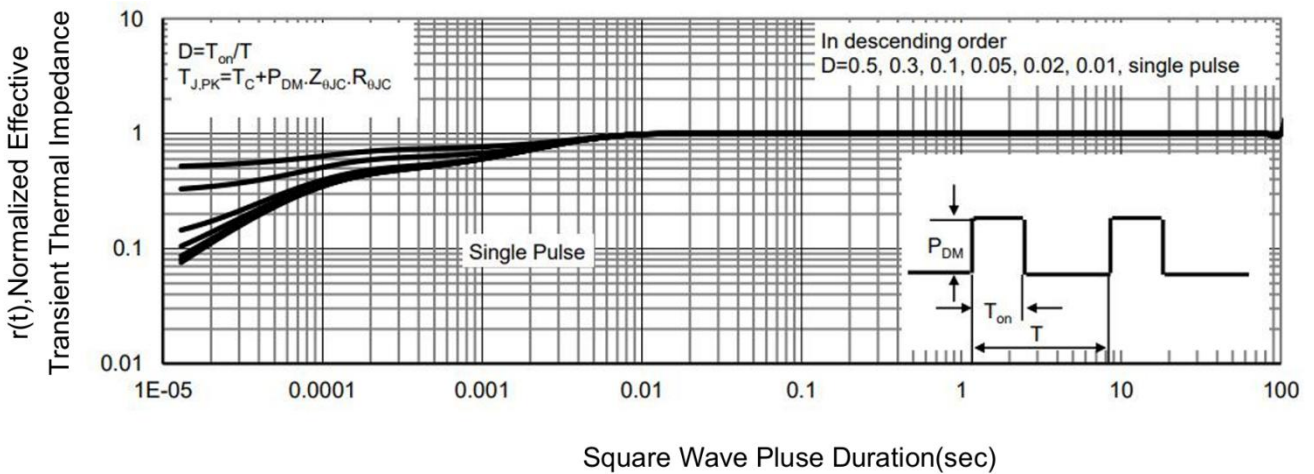
**Figure 8 Safe Operation Area**



**Figure 9 Power De-rating**

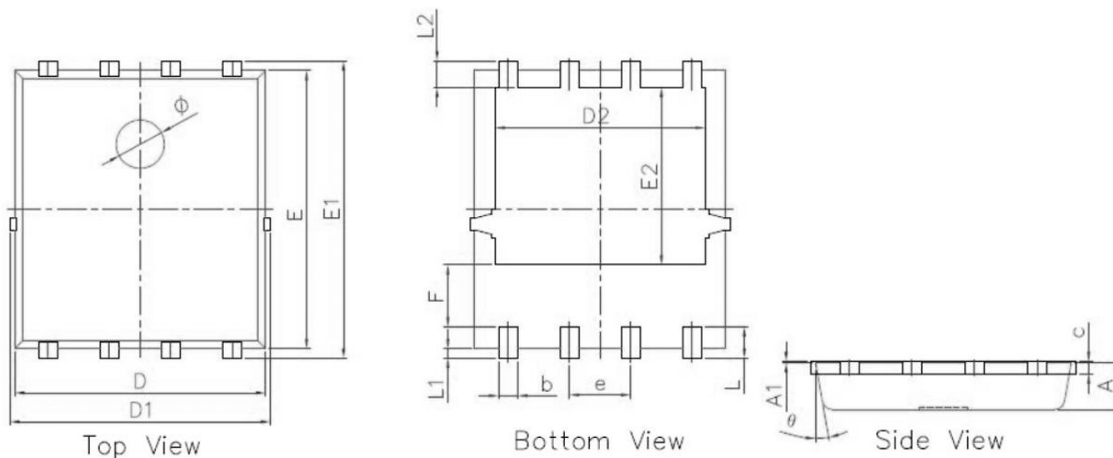


**Figure 10 Current De-rating**



**Figure 11 Normalized Maximum Transient Thermal Impedance**

### PDFN5\*6-8L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A1	0.000	0.050	0.000	0.002
b	0.350	0.500	0.014	0.020
C	0.200	0.300	0.008	0.012
D	5.100	5.300	0.201	0.209
D1	5.100	5.500	0.201	0.217
D2	4.250	4.450	0.167	0.175
E	5.700	5.800	0.224	0.228
E1	6.000	6.300	0.236	0.248
E2	3.570	3.770	0.141	0.148
e	1.270 BSC.		0.050 BSC.	
F	1.180	1.380	0.046	0.054
L	0.550	0.750	0.022	0.030
L1	0.150	0.250	0.006	0.010
L2	0.450	0.650	0.018	0.026
$\Phi$	0.900	1.100	0°	12°
$\theta$	8°	12°	8°	12°